

Basic Electronic Circuits

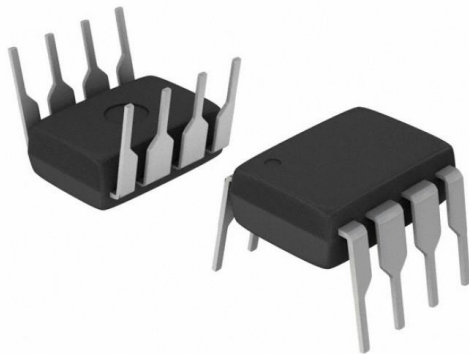
(IEC-103)

Lecture-14

555 Timer

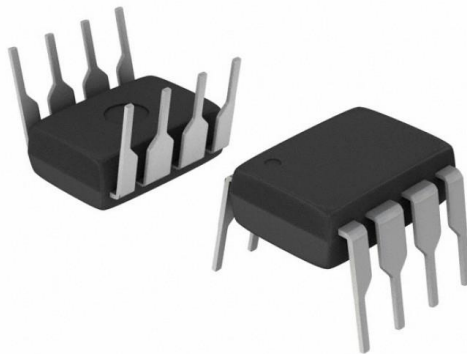
555 IC

The IC 555 is an 8-pin Integrated Circuit (IC) that is capable of producing accurate time delays and/or oscillations.

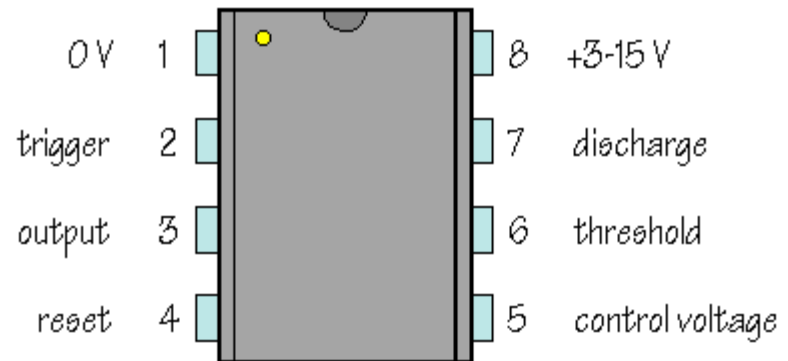


555 IC

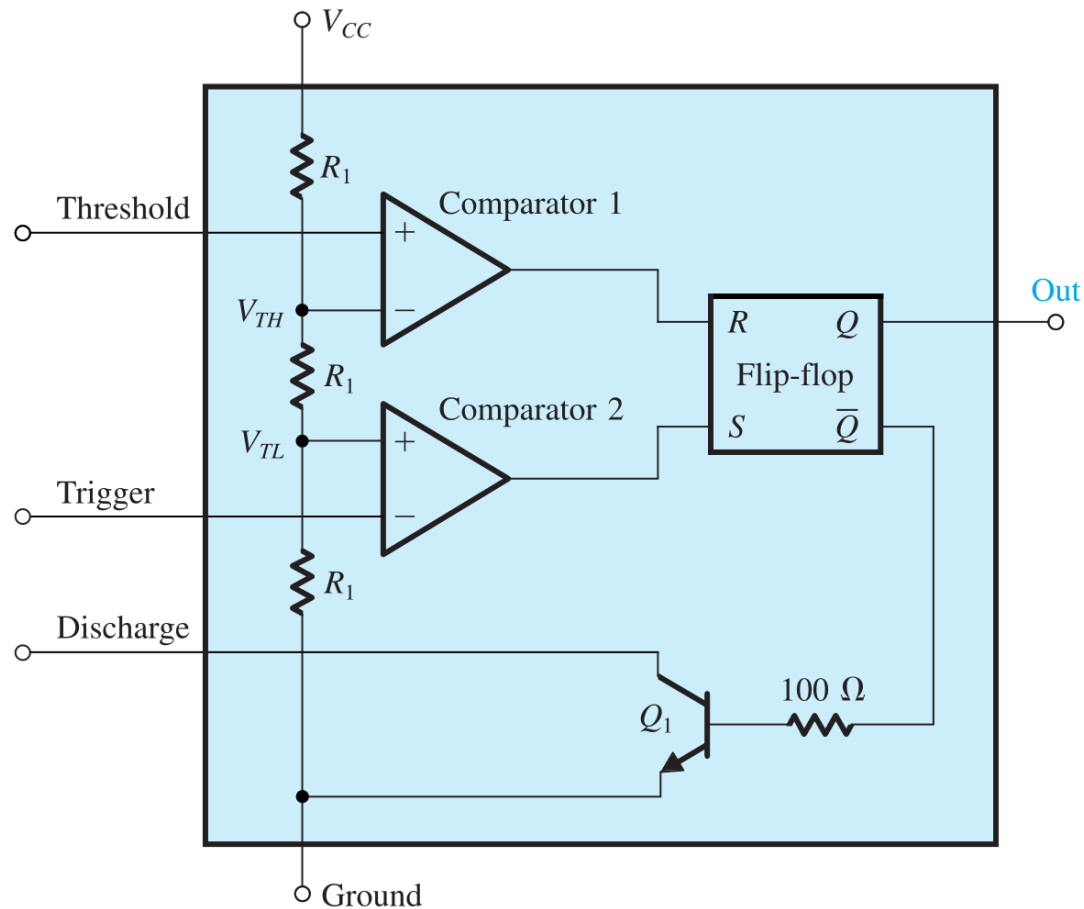
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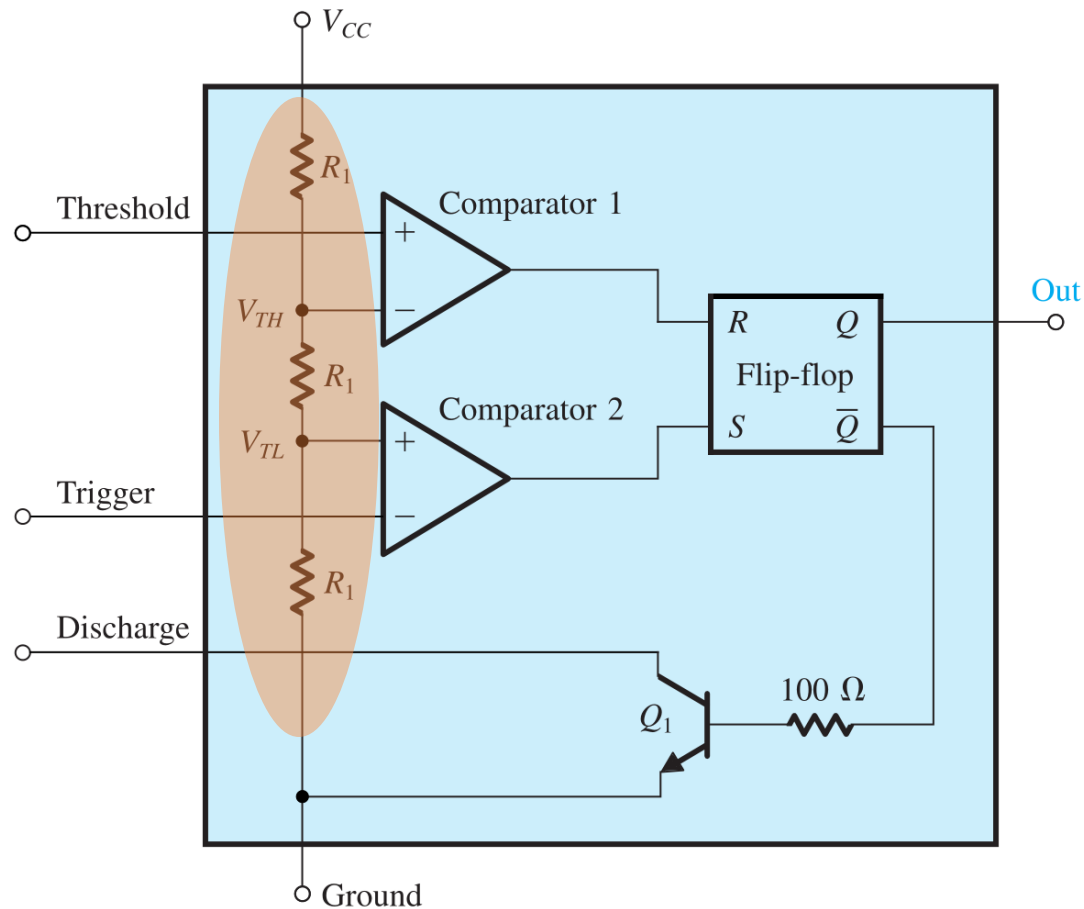
DIP chip (Dual-Inline package)



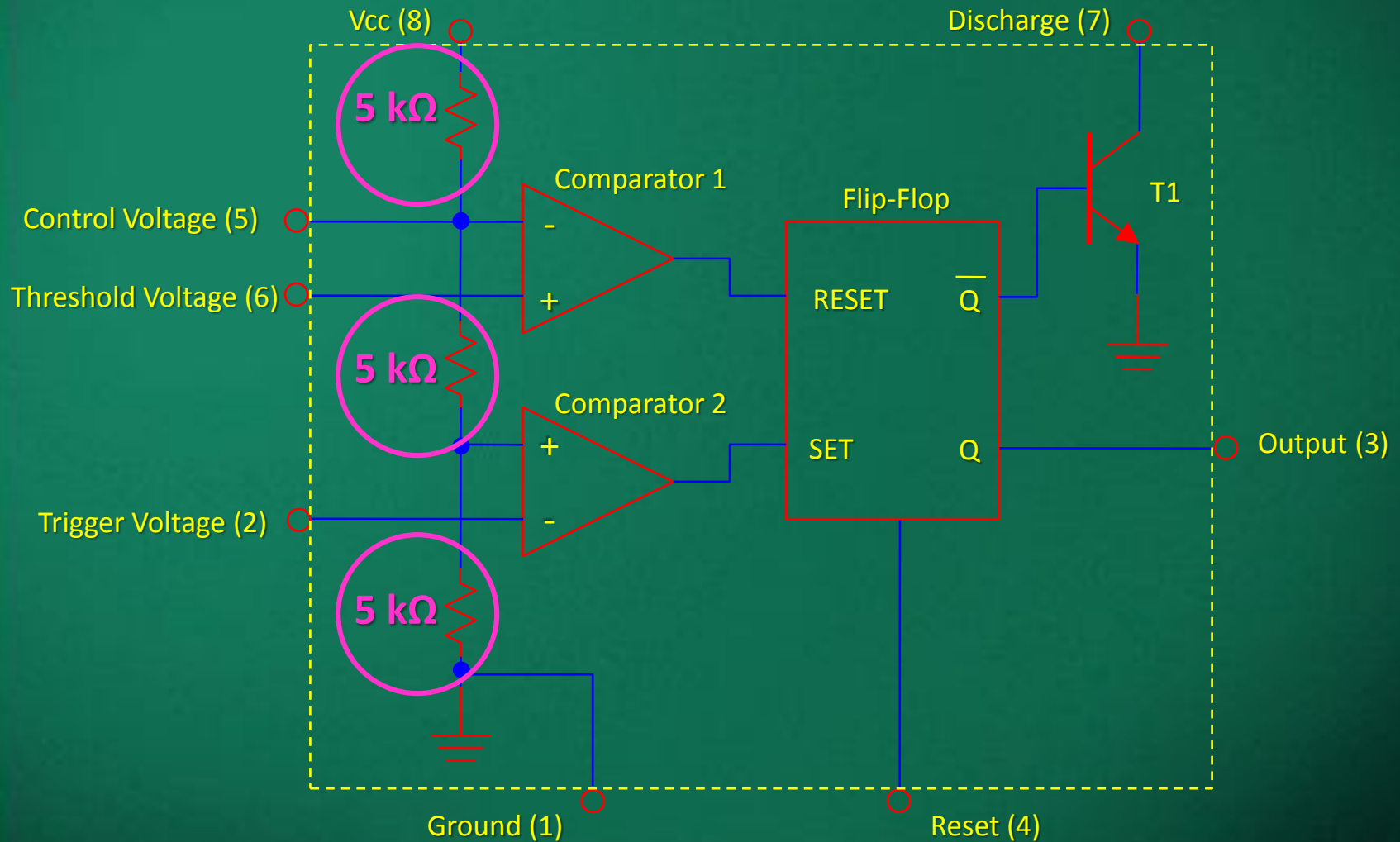
555 IC (Internal Circuit Diagram)



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555 IC (Internal Circuit Diagram)



Truth Table of RS Flip Flop

S	R	Q	State
0	0	Previous State	No Change
0	1	0	Reset
1	0	1	Set
1	1	?	Forbidden

Modes of Operation

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Time Delay Mode

In the time delay mode, the delay is controlled by one external resistor and capacitor.

Example: Turn a light on in a delayed amount of time (just turn on or off once)

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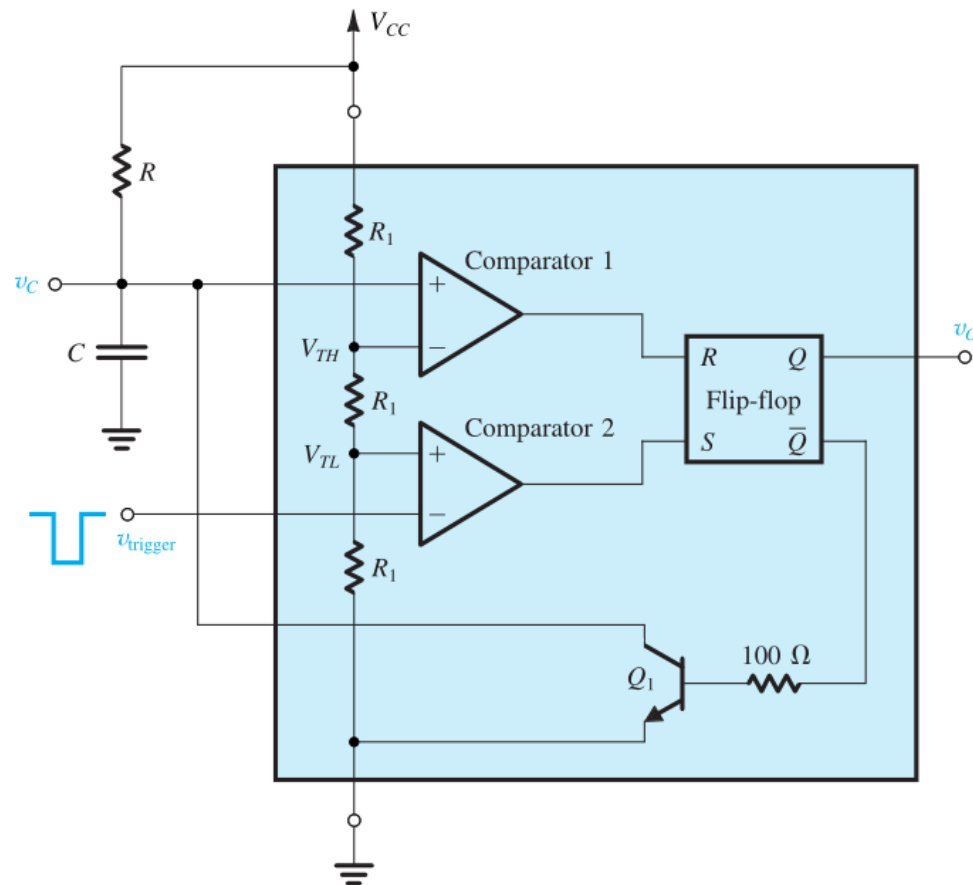
Example: Turn a light on in a delayed amount of time (just turn on or off once)

Oscillator Mode

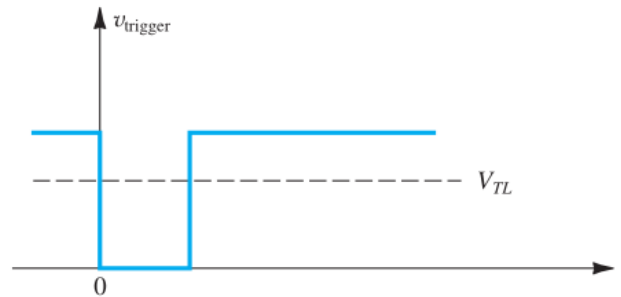
In the oscillator mode, the frequency of oscillation are controlled with two external resistors and one capacitor.

Example: Can make a light flash a specific rate (can turn on and off repeatedly)

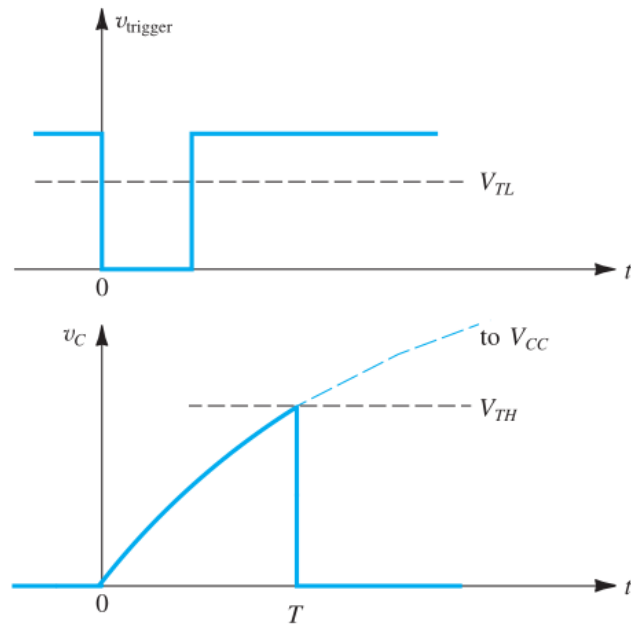
Mono stable Multivibrator



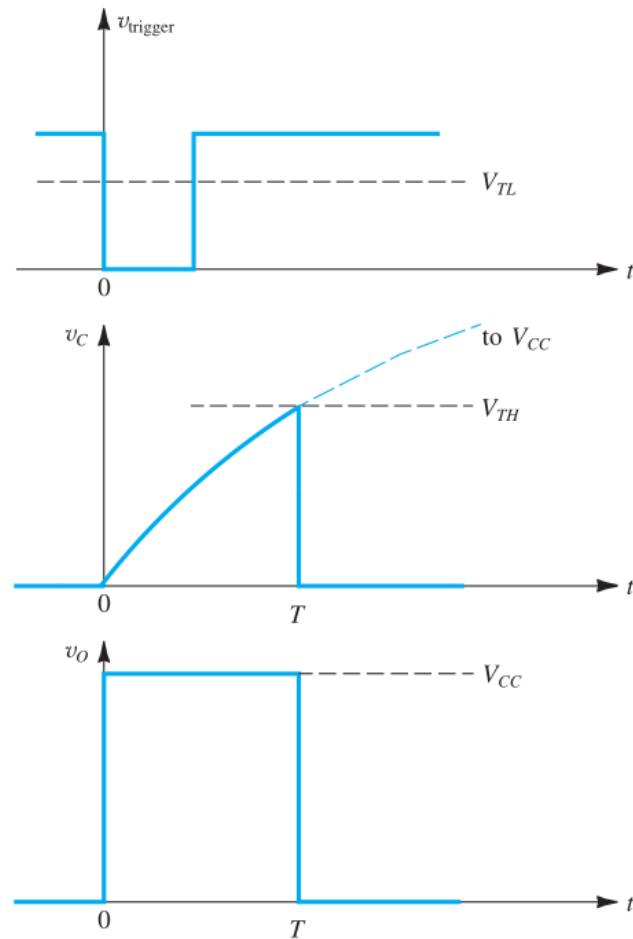
Mono stable Multivibrator



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Mono stable Multivibrator

Output pulse duration

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$$v_c = V_{CC} \left(1 - e^{-t/RC} \right)$$

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$$v_c = V_{TH} = \frac{2}{3} V_{CC} \text{ at } t = T$$

Mono stable Multivibrator

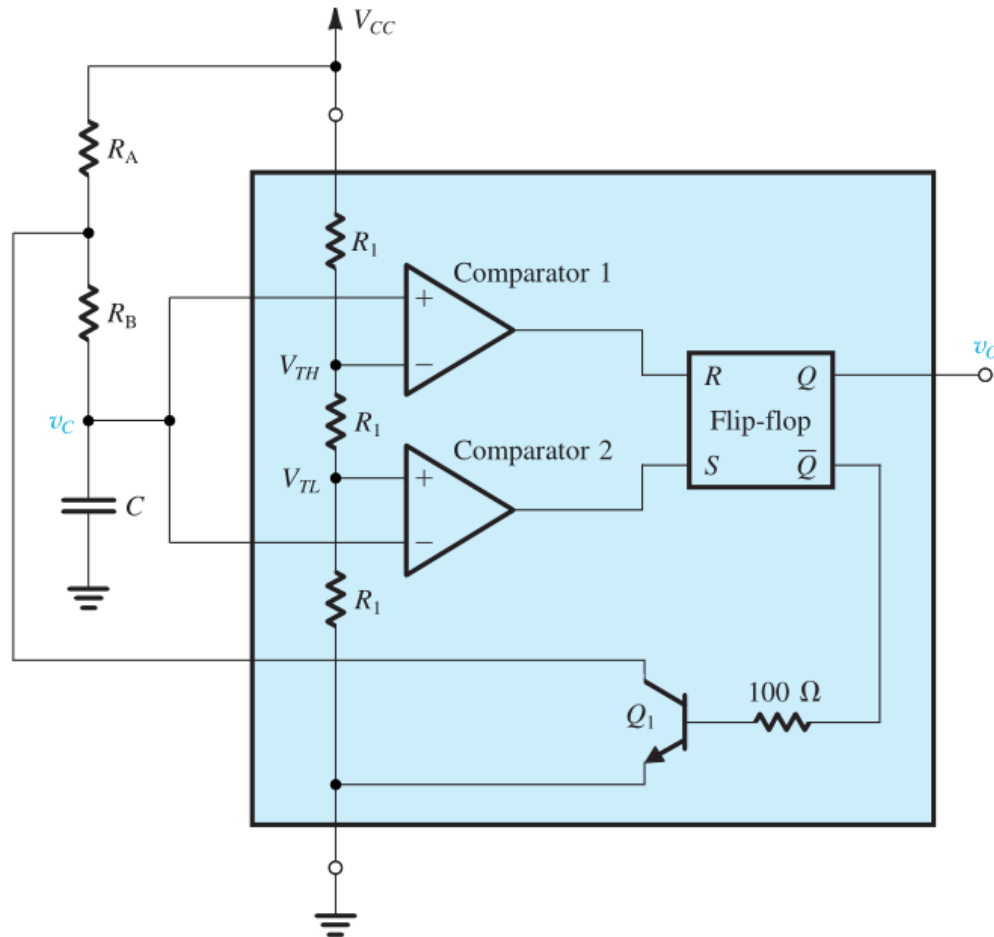
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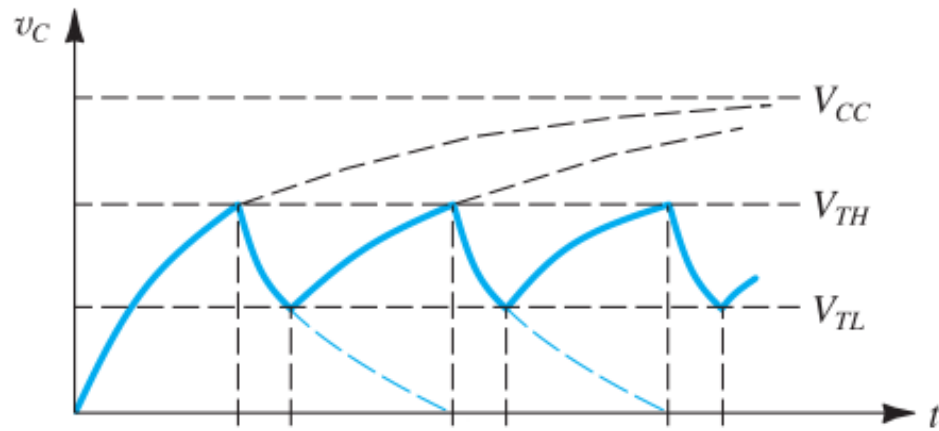
$$v_c = V_{TH} = \frac{2}{3} V_{CC} \text{ at } t = T$$

$$\therefore T = RC \ln(3) = 1.1RC$$

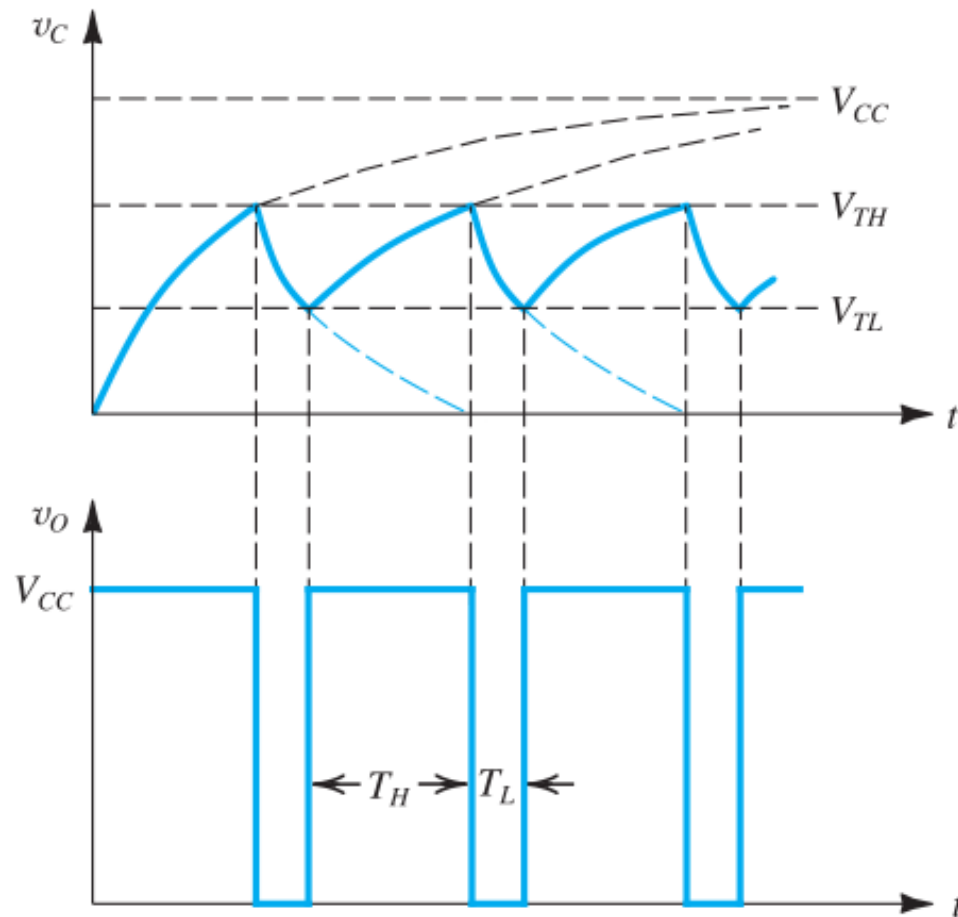
Astable Multivibrator



Astable Multivibrator



Astable Multivibrator



Astable Multivibrator

Turn on time calculation

Astable Multivibrator

Turn on time calculation

$$v_c(t) = v_c(\infty) + (v_c(0) - v_c(\infty))e^{-t/((R_A + R_B)C)}$$

Astable Multivibrator

Turn on time calculation

$$v_c(t) = v_c(\infty) + (v_c(0) - v_c(\infty))e^{-t/((R_A + R_B)C)}$$

$$v_c(T_{ON}) = V_{TH} = V_{CC} + (V_{TL} - V_{CC})e^{-T_{ON}/((R_A + R_B)C)}$$

Astable Multivibrator

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$$(2/3)V_{CC} = V_{CC} + ((1/3)V_{CC} - V_{CC})e^{-T_{ON}/((R_A + R_B)C)}$$

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$$(2/3) = 1 + ((1/3) - 1)e^{-T_{ON}/((R_A + R_B)C)}$$

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$$\Rightarrow -T_{\text{ON}} / ((R_A + R_B)C) = \ln(1/2)$$

$$\Rightarrow T_{\text{ON}} = (R_A + R_B)C \ln(2)$$

Astable Multivibrator

Turn on time calculation

$$\Rightarrow -T_{\text{ON}}/((R_A + R_B)C) = \ln(1/2)$$

$$\Rightarrow T_{\text{ON}} = (R_A + R_B)C \ln(2)$$

$$\Rightarrow T_{\text{ON}} = 0.69(R_A + R_B)C$$

Mono stable Multivibrator

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Mono stable Multivibrator

Time period of oscillations

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$$T = T_{\text{ON}} + T_{\text{OFF}} = 0.69(R_A + R_B)C + 0.69R_B C$$

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$$\text{DutyRatio} = \frac{T_{\text{ON}}}{T} = \frac{T_{\text{ON}}}{T_{\text{ON}} + T_{\text{OFF}}} = \frac{0.69(R_A + R_B)C}{0.69(R_A + 2R_B)C} = \frac{(R_A + R_B)}{(R_A + 2R_B)}$$

Transistors

Transistor

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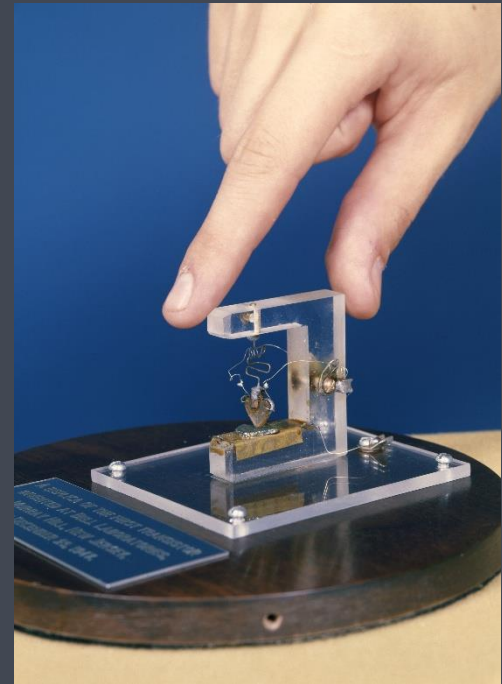
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 - **large numbers of extremely small transistors can be manufactured as a single integrated circuit.**
 - **Less power hungry and more efficient.**
 - **More life.**
 - **Mechanically strong.**
- ❑ **Invented in 1948 in Bell Labs.**

First Working Transistor



First Working Transistor



**Invented by
Shockley,
Bardeen, and
Brattain.**

**Jointly
awarded
Nobel Prize
in Physics in
1956.**

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- ❑ **The switch current can be controlled by either current or voltage.**
- ❑ **They can be used either as switches or as amplifiers.**

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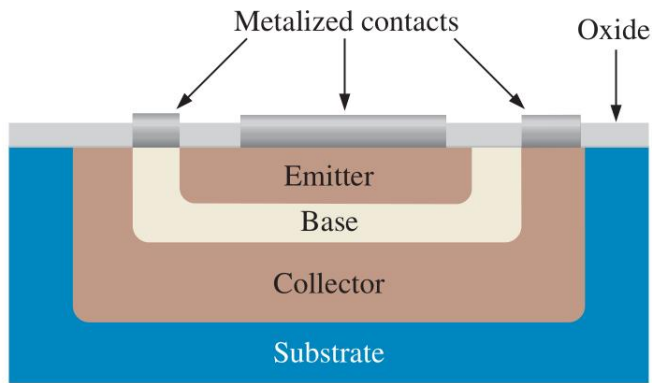
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- ❑ Two types of transistors
 - **Bipolar Junction Transistors (BJT)**
 - **Field Effect Transistors (FET)**

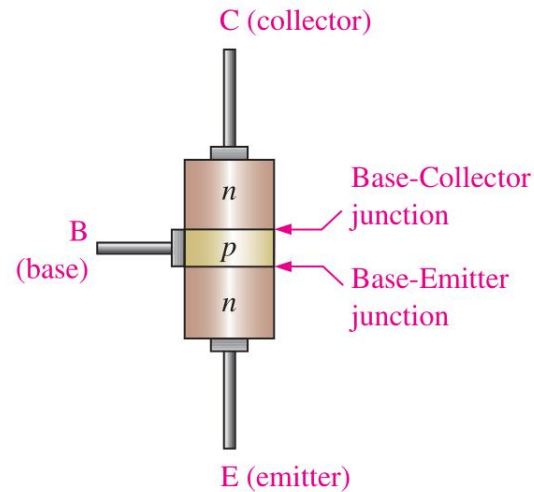
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- ❑ Two types BJTs
 - **NPN** Transistor
 - **PNP** Transistor

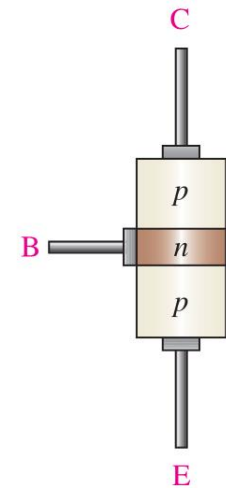
BJT Construction



(a) Basic epitaxial planar structure

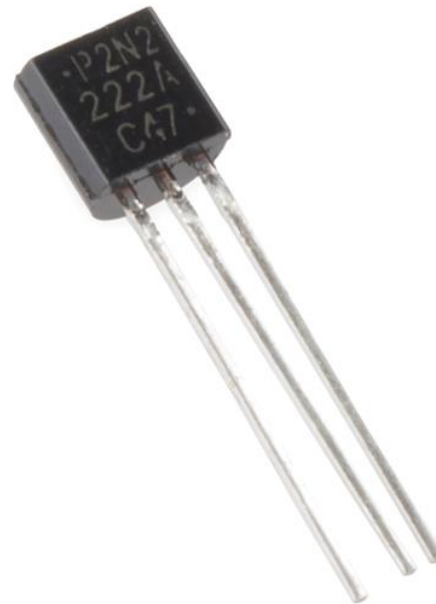
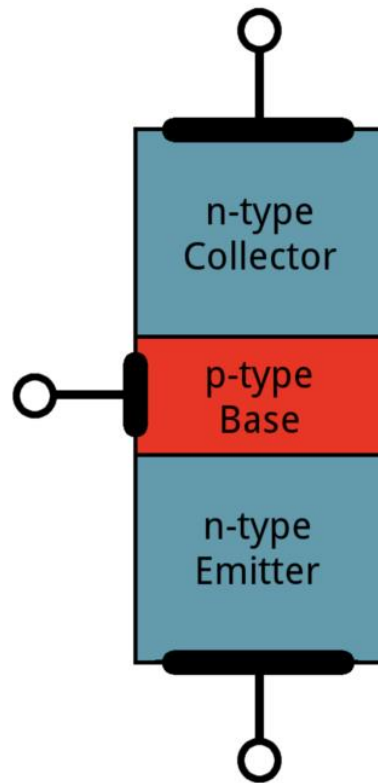


(b) npn

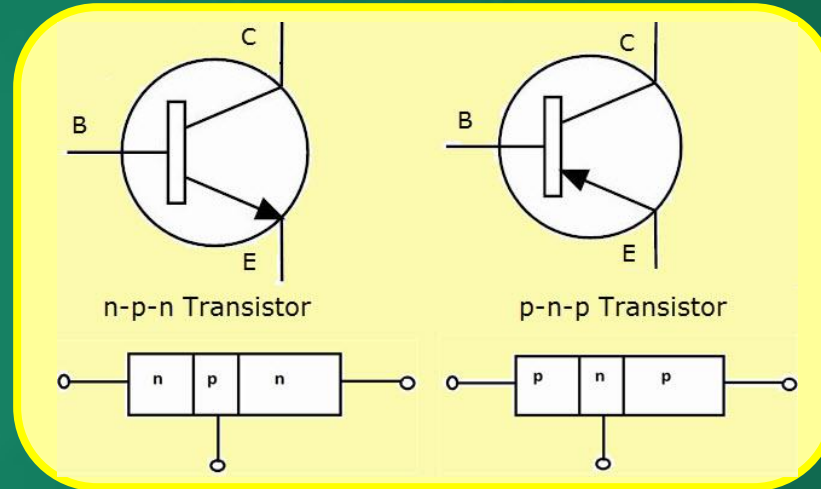


(c) pnp

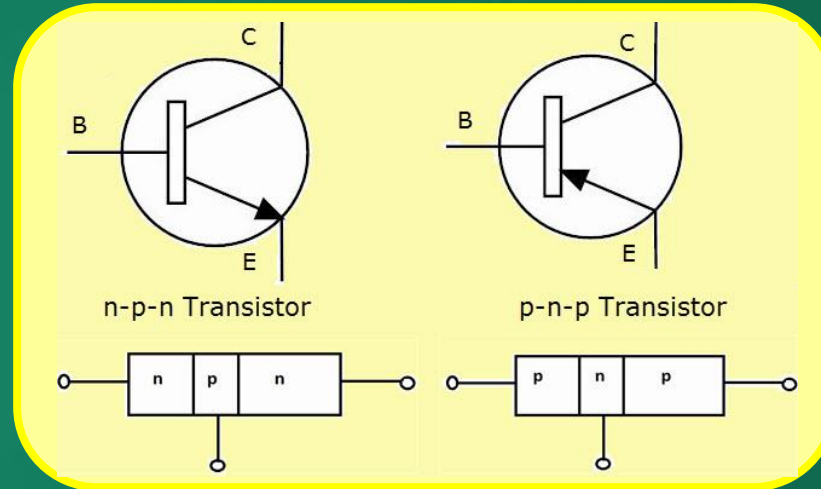
Transistor Symbol



Transistor Construction

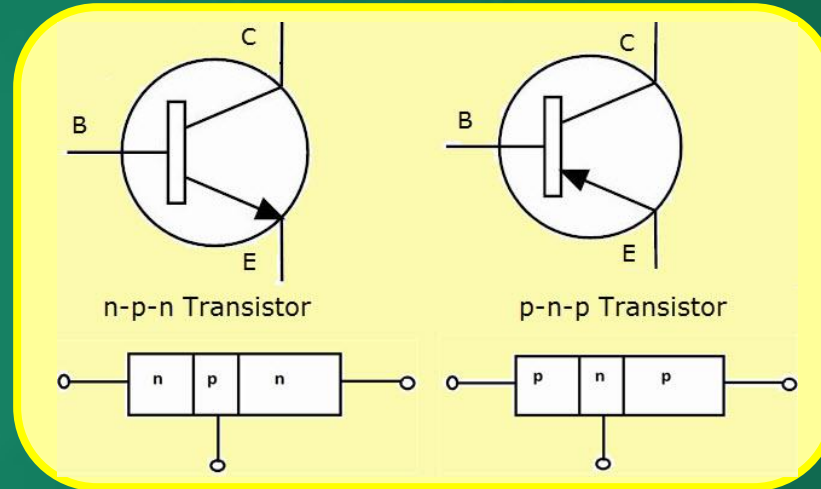


Transistor Construction



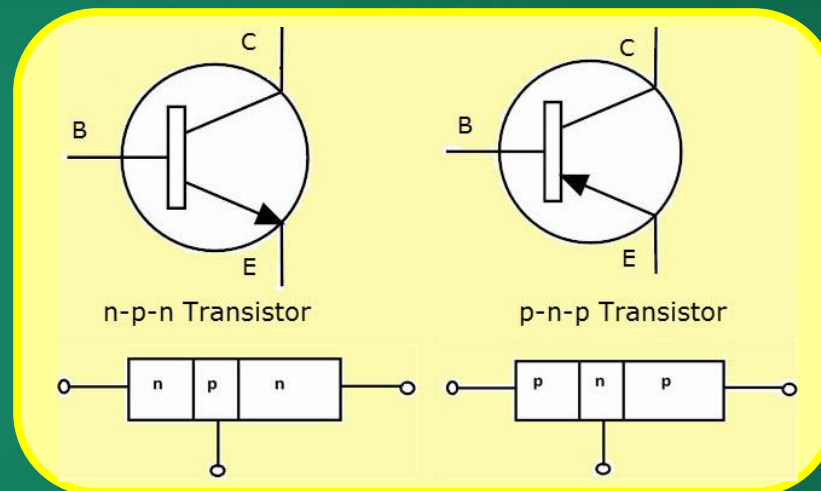
□ **Consists of 3 sections and 2 junctions.**

Transistor Construction



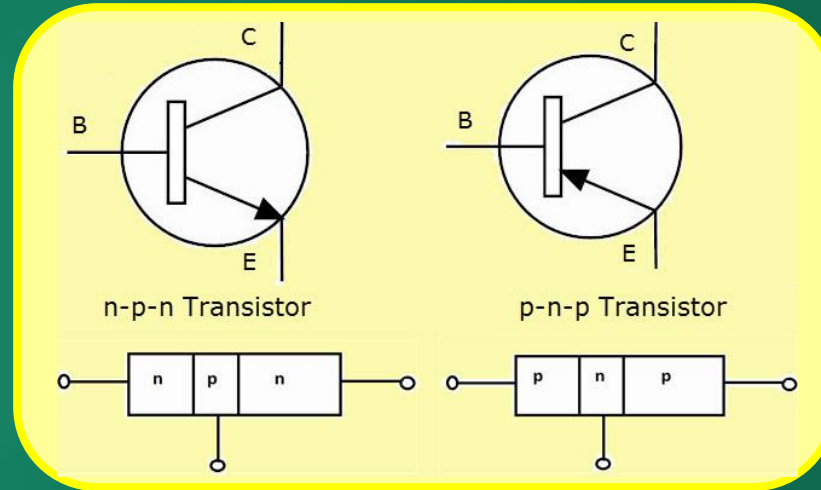
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Transistor Construction



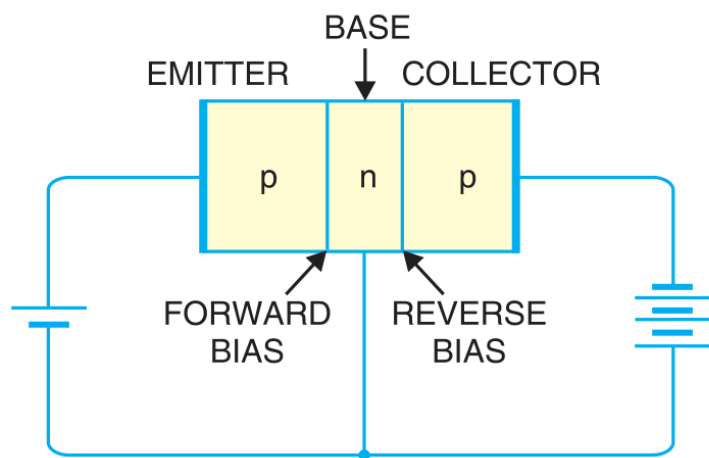
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- ❑ **The base is very thin and collector is much wider than emitter**

Transistor Construction

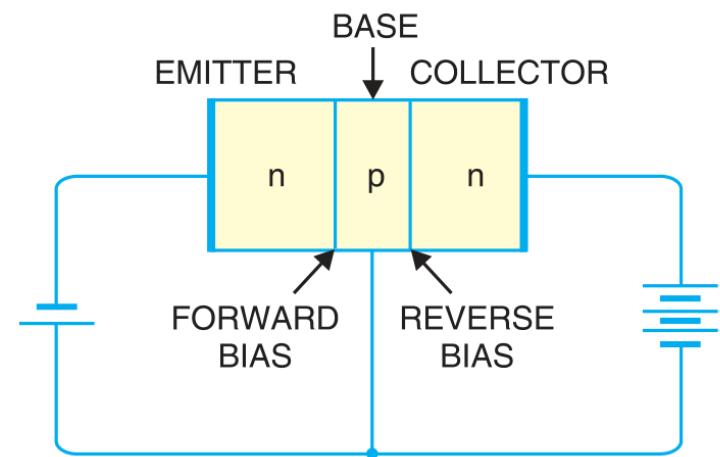
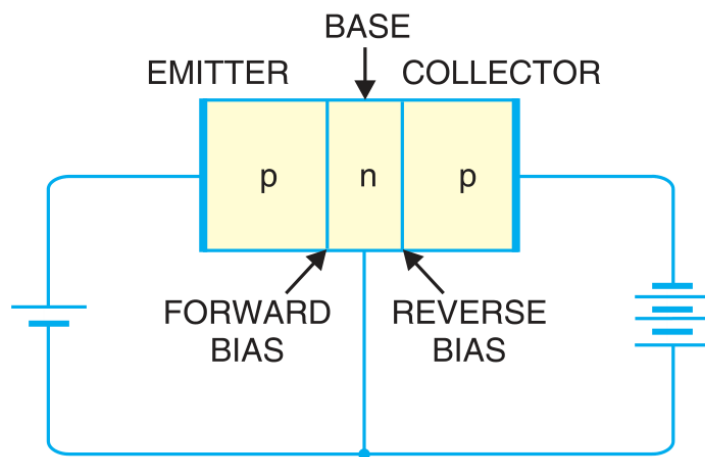


- ❑ **Consists of 3 sections and 2 junctions.**
- ❑ **3 sections are Emitter, Base, and Collector**
- ❑ **The base is very thin and collector is much wider than emitter**
- ❑ **The base is very lightly doped, emitter is heavily doped and collector is moderately doped.**

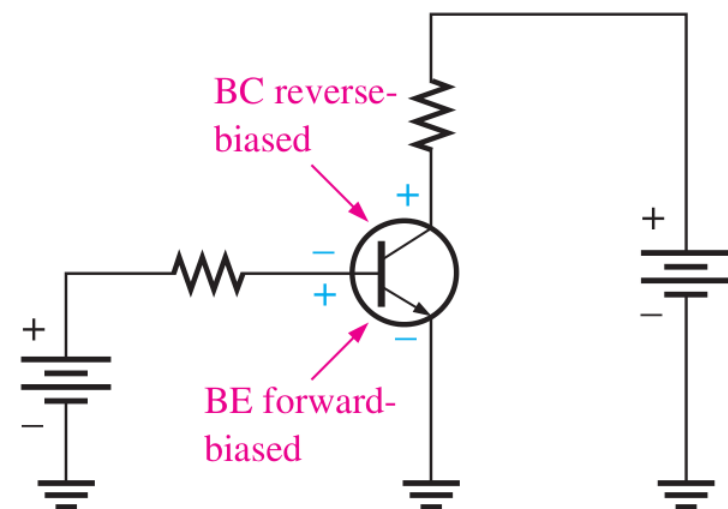
Transistor Junction Biasing



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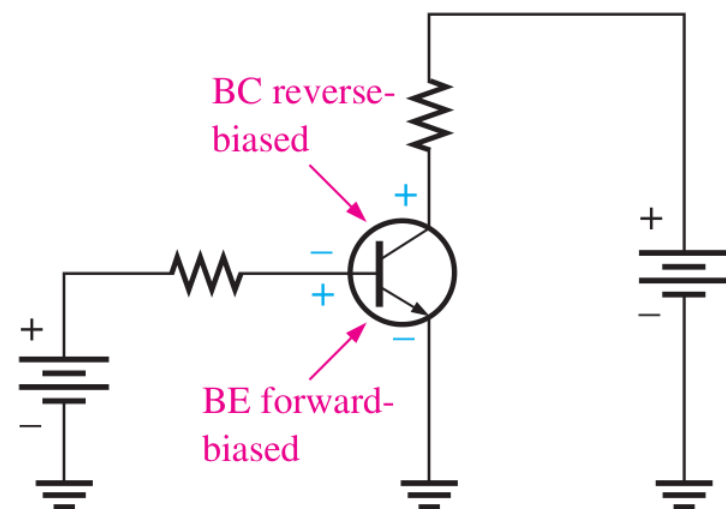


Transistor Junction Biasing

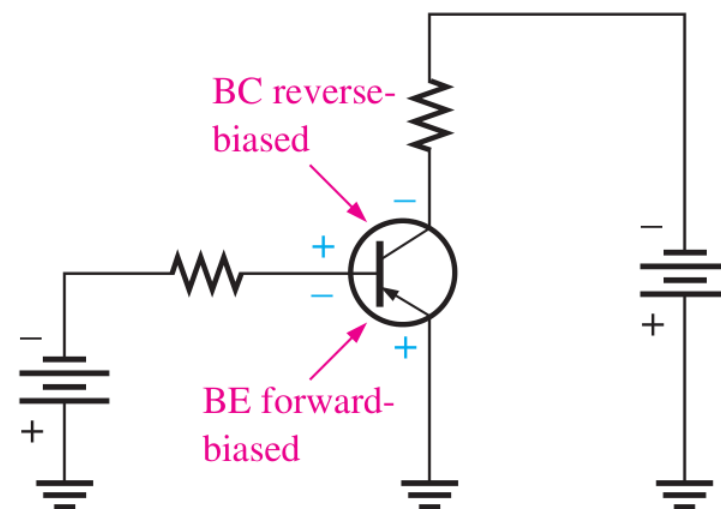


(a) npn

Transistor Junction Biasing

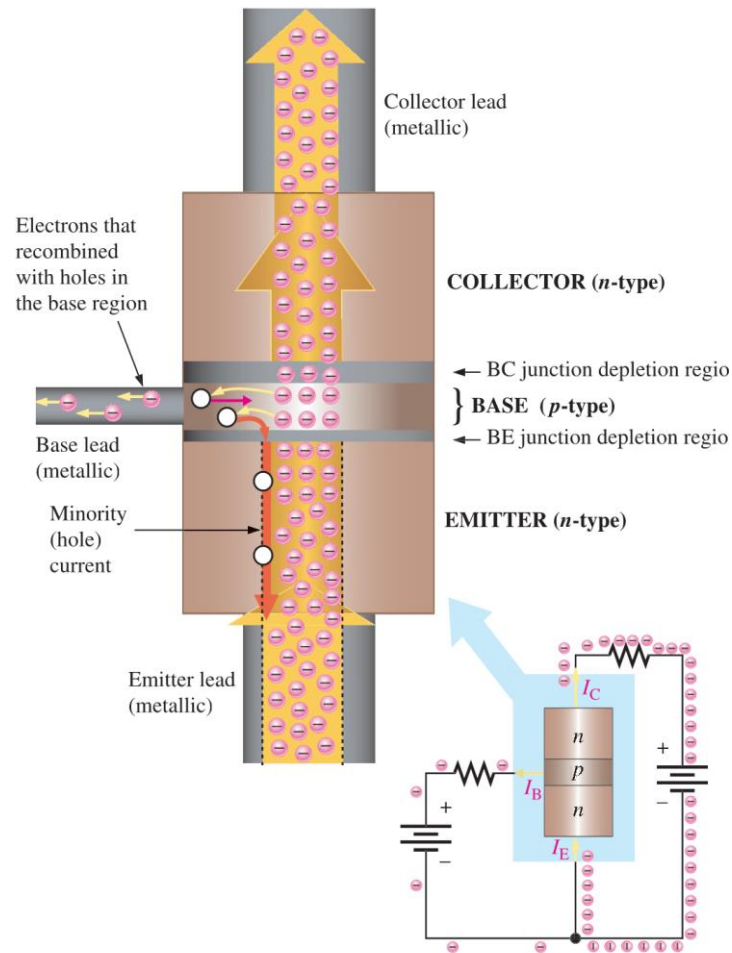


(a) *nnp*

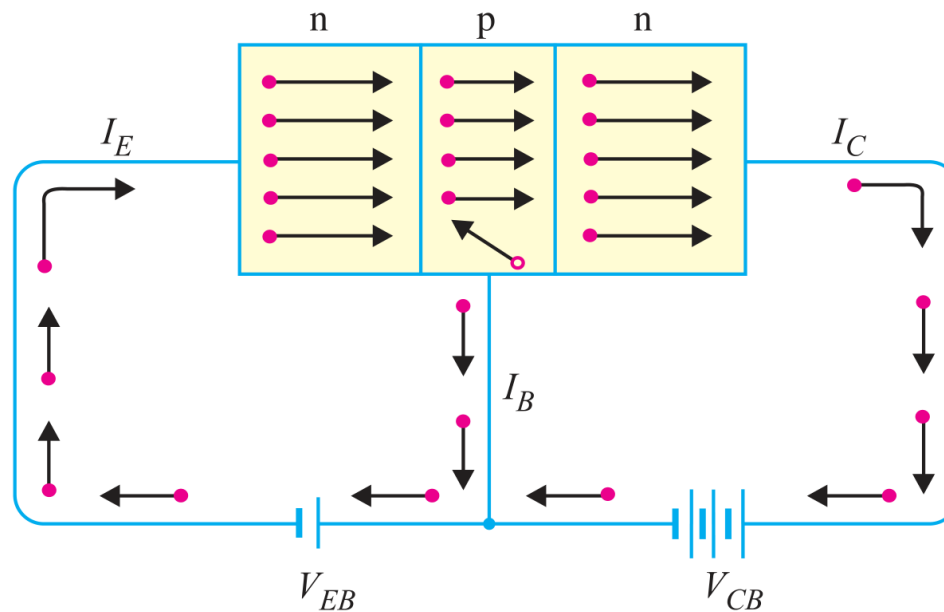


(b) *pnp*

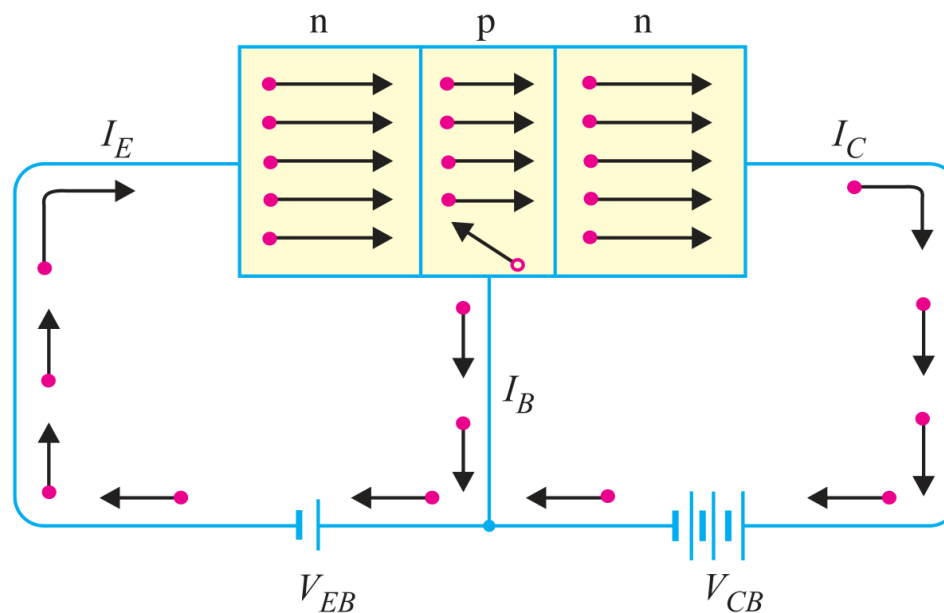
BJT Operation showing Electron Flow



Transistor Junction Biasing

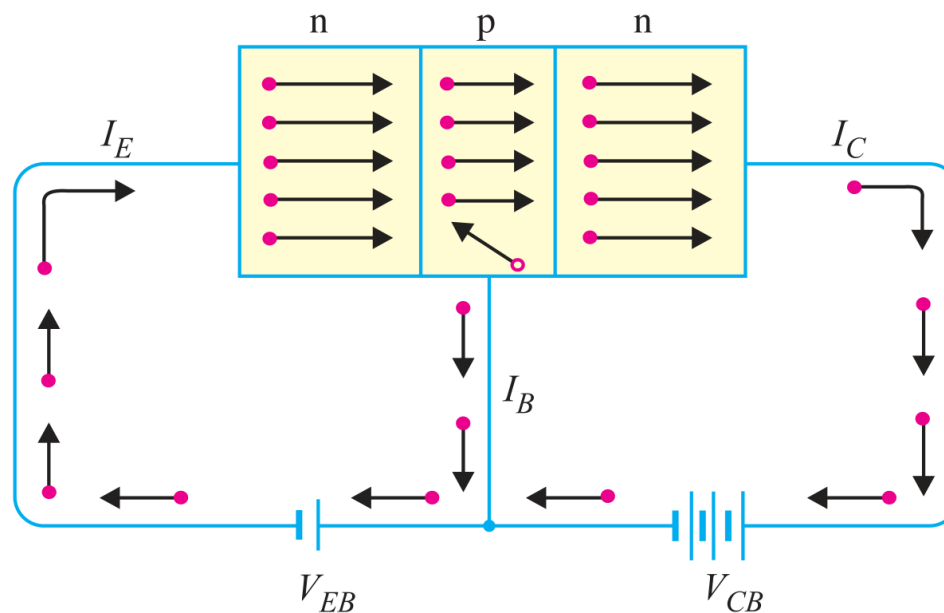


Transistor Junction Biasing



$$I_E = I_B + I_C$$

Transistor Junction Biasing

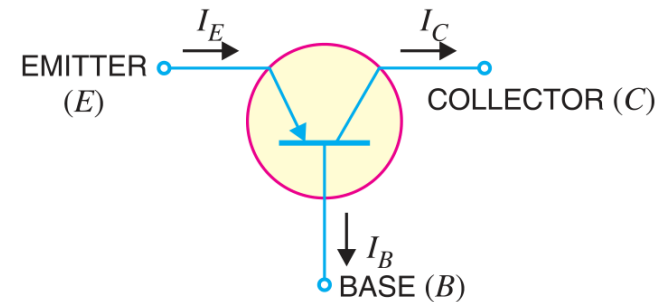
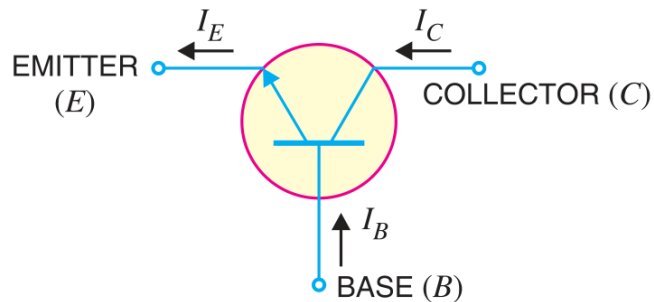
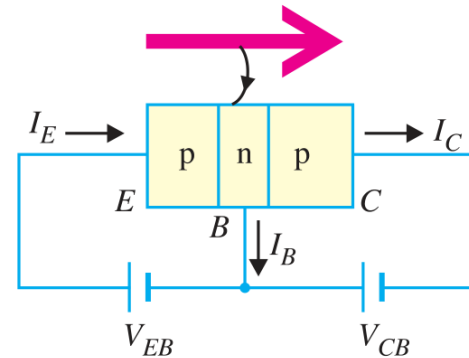
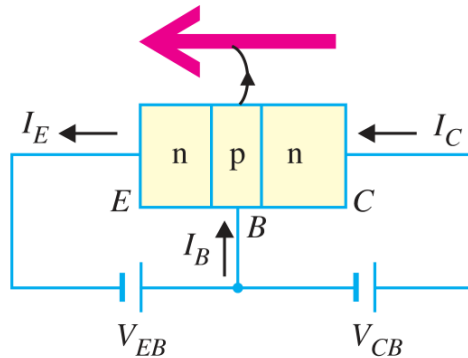


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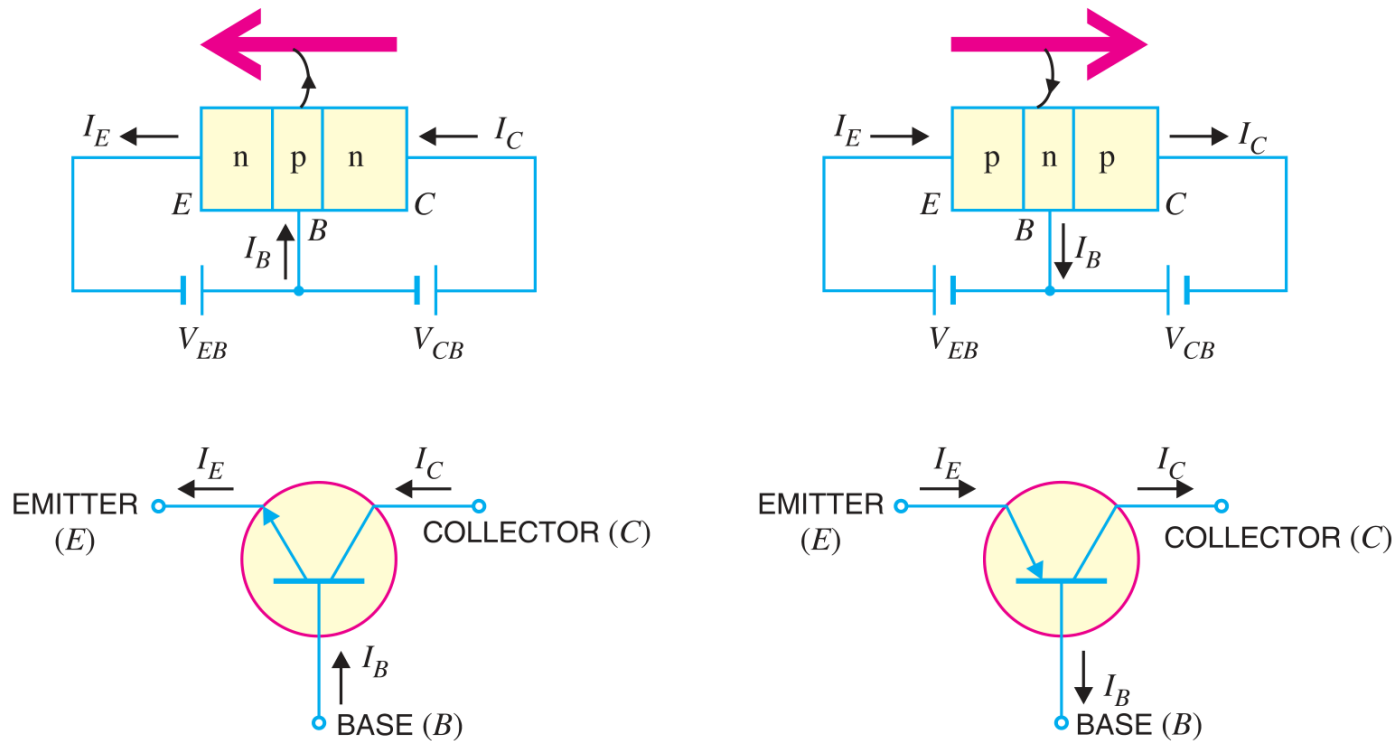
$$I_C = \alpha I_E$$

$$I_C = \beta I_B$$

Transistor Symbols



Transistor Symbols



Arrow indicates the direction of conventional current flow with forward bias.